



THE DATASHEET OF MRF19090



RF Power Field Effect Transistors

N-Channel Enhancement-Mode Lateral MOSFETs

Designed for Class AB PCN and PCS base station applications with frequencies from 1900 to 2000 MHz. Suitable for CDMA, TDMA, GSM, and multicarrier amplifier applications.

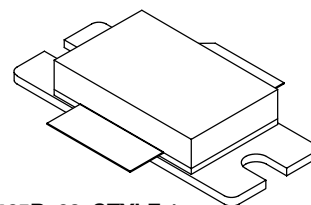
- Typical CDMA Performance: 1990 MHz, 26 Volts
 IS-95 CDMA Pilot, Sync, Paging, Traffic Codes 8 Through 13
 Output Power — 9 Watts Avg.
 Power Gain — 10 dB
 Adjacent Channel Power —
 885 kHz: -47 dBc @ 30 kHz BW
 1.25 MHz: -55 dBc @ 12.5 kHz BW
 2.25 MHz: -55 dBc @ 1 MHz BW
- Capable of Handling 10:1 VSWR, @ 26 Vdc, 1960 MHz, 90 Watts CW Output Power

Features

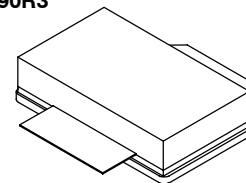
- Internally Matched for Ease of Use
- High Gain, High Efficiency and High Linearity
- Integrated ESD Protection
- Designed for Maximum Gain and Insertion Phase Flatness
- Excellent Thermal Stability
- Characterized with Series Equivalent Large-Signal Impedance Parameters
- RoHS Compliant
- In Tape and Reel. R3 Suffix = 250 Units per 56 mm, 13 inch Reel.

MRF19090R3
MRF19090SR3

1930-1990 MHz, 90 W, 26 V
LATERAL N-CHANNEL
RF POWER MOSFETs



CASE 465B-03, STYLE 1
NI-880
MRF19090R3



CASE 465C-02, STYLE 1
NI-880S
MRF19090SR3

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Table 1. Maximum Ratings

Rating	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	-0.5, +65	Vdc
Gate-Source Voltage	V_{GS}	-0.5, +15	Vdc
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	270 1.54	W W/ $^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 65 to +150	$^\circ\text{C}$
Case Operating Temperature	T_C	150	$^\circ\text{C}$
Operating Junction Temperature	T_J	200	$^\circ\text{C}$

Table 2. Thermal Characteristics

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	0.65	$^\circ\text{C}/\text{W}$

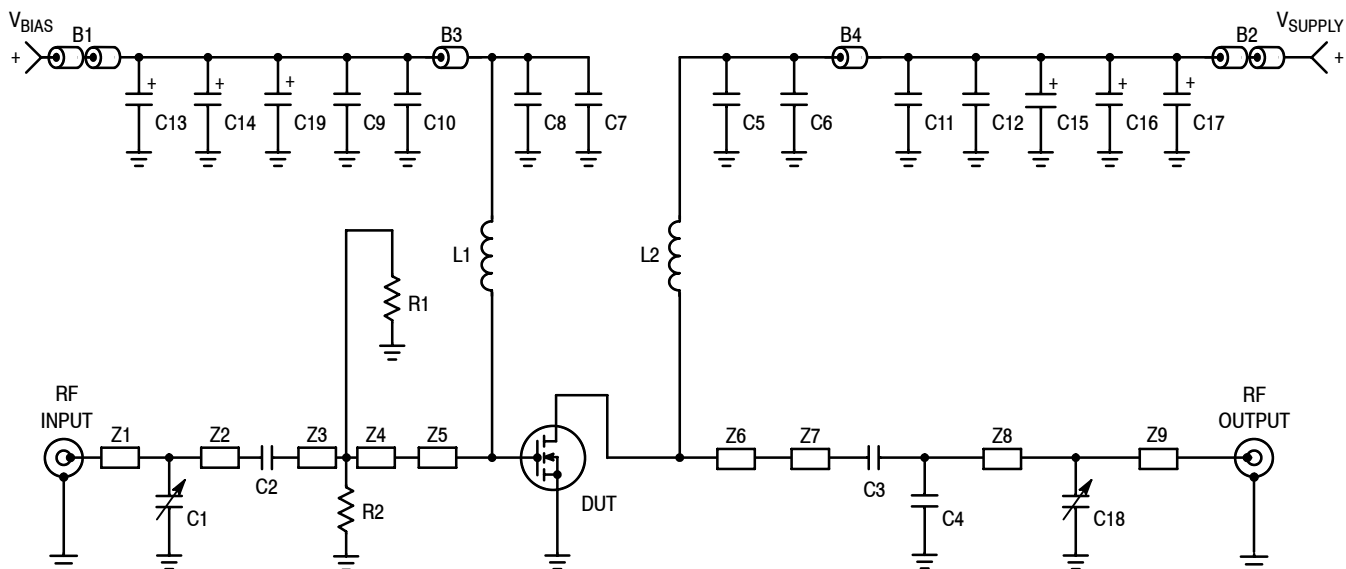
Table 3. ESD Protection Characteristics

Test Conditions	Class
Human Body Model	1 (Minimum)
Machine Model	M3 (Minimum)

Table 4. Electrical Characteristics ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
Off Characteristics					
Drain-Source Breakdown Voltage ($V_{GS} = 0\text{ Vdc}$, $I_D = 100\ \mu\text{A}$)	$V_{(BR)DSS}$	65	—	—	Vdc
Zero Gate Voltage Drain Current ($V_{DS} = 28\text{ Vdc}$, $V_{GS} = 0\text{ Vdc}$)	I_{DSS}	—	—	10	μAdc
Gate-Source Leakage Current ($V_{GS} = 5\text{ Vdc}$, $V_{DS} = 0\text{ Vdc}$)	I_{GSS}	—	—	1	μAdc
On Characteristics					
Forward Transconductance ($V_{DS} = 10\text{ Vdc}$, $I_D = 3\text{ Adc}$)	g_{fs}	—	7.2	—	S
Gate Threshold Voltage ($V_{DS} = 10\text{ Vdc}$, $I_D = 300\ \mu\text{Adc}$)	$V_{GS(th)}$	2.0	—	4.0	Vdc
Gate Quiescent Voltage ($V_{DS} = 26\text{ Vdc}$, $I_D = 750\text{ mAdc}$)	$V_{GS(Q)}$	2.5	3.8	4.5	Vdc
Drain-Source On-Voltage ($V_{GS} = 10\text{ Vdc}$, $I_D = 1\text{ Adc}$)	$V_{DS(on)}$	—	0.10	—	Vdc
Dynamic Characteristics					
Reverse Transfer Capacitance (1) ($V_{DS} = 26\text{ Vdc}$, $V_{GS} = 0$, $f = 1\text{ MHz}$)	C_{rss}	—	4.2	—	pF
Functional Tests (In Freescale Test Fixture)					
Two-Tone Common-Source Amplifier Power Gain ($V_{DD} = 26\text{ Vdc}$, $P_{out} = 90\text{ W PEP}$, $I_{DQ} = 750\text{ mA}$, $f = 1930\text{ MHz}$ and 1990 MHz , Tone Spacing = 100 kHz)	G_{ps}	10	11.5	—	dB
Two-Tone Drain Efficiency ($V_{DD} = 26\text{ Vdc}$, $P_{out} = 90\text{ W PEP}$, $I_{DQ} = 750\text{ mA}$, $f = 1930\text{ MHz}$ and 1990 MHz , Tone Spacing = 100 kHz)	η	33	35	—	%
3rd Order Intermodulation Distortion ($V_{DD} = 26\text{ Vdc}$, $P_{out} = 90\text{ W PEP}$, $I_{DQ} = 750\text{ mA}$, $f = 1930\text{ MHz}$ and 1990 MHz , Tone Spacing = 100 kHz)	IMD	—	-30	-28	dBc
Input Return Loss ($V_{DD} = 26\text{ Vdc}$, $P_{out} = 90\text{ W PEP}$, $I_{DQ} = 750\text{ mA}$, $f = 1930\text{ MHz}$ and 1990 MHz , Tone Spacing = 100 kHz)	IRL	—	-12	—	dB
P_{out} , 1 dB Compression Point ($V_{DD} = 26\text{ Vdc}$, $P_{out} = 90\text{ W CW}$, $f = 1990\text{ MHz}$)	P1dB	—	90	—	W

1. Part is internally matched both on input and output.

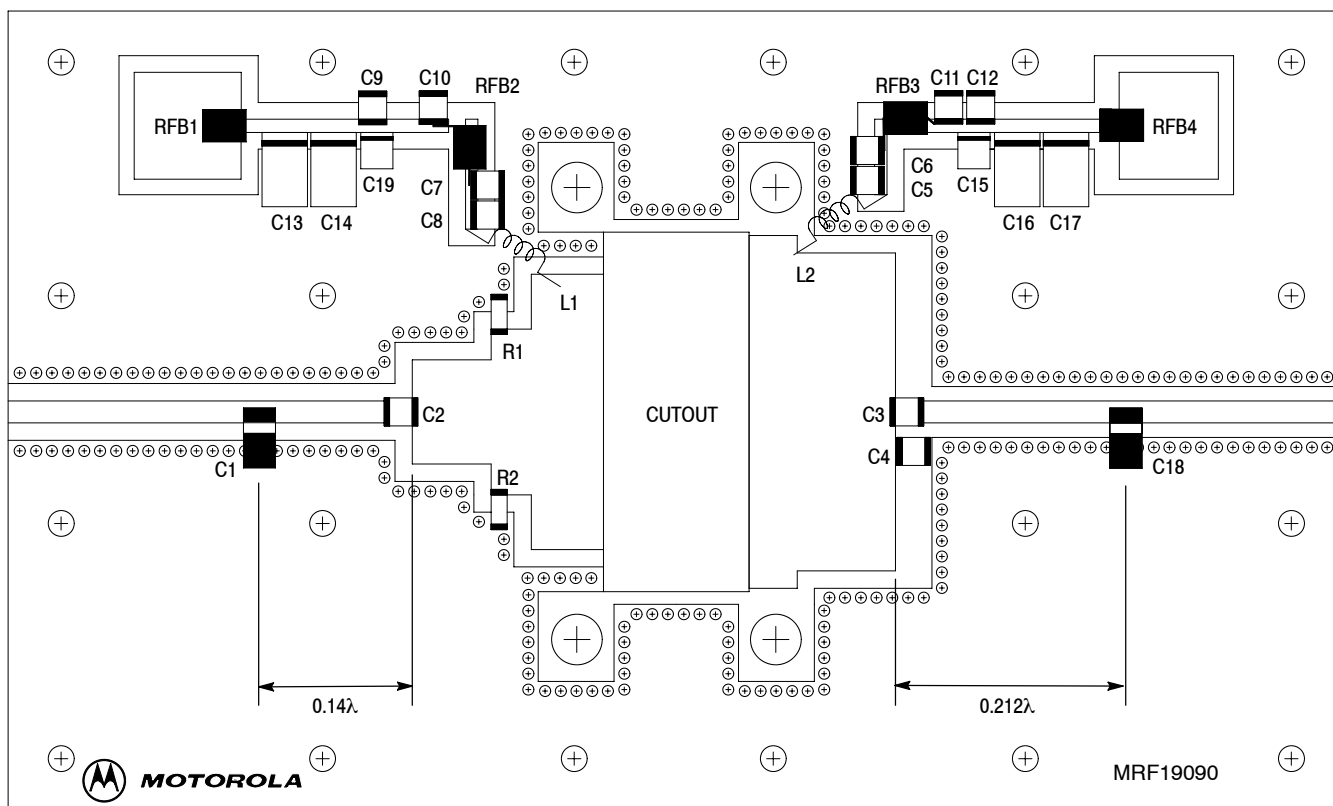


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B1, B2	2 Ferrite Beads, Round, Ferroxcube #56-590-65-3B	L1, L2	8 Turns, #26 AWG, 0.085" OD, 0.330" Long, Copper Wire
B3, B34	Ferrite Beads, Surface Mount, Ferroxcube	R1, R2	270 Ω , 1/4 W Chip Resistors, Garrett Instruments #RM73B2B271JT
C1, C18	0.4 - 2.5 pF Variable Capacitors, Johanson Gigatrim #27285	Z1	ZO = 50 Ohms
C2, C5, C8	10 pF Chip Capacitors, ATC #100B100CCA500X	Z2	ZO = 50 Ohms, Lambda = 0.123
C3	12 pF Chip Capacitor, ATC #100B120CCA500X	Z3	ZO = 15.24 Ohms, Lambda = 0.0762
C4	0.3 pF Chip Capacitor, ATC #100B0R3CCA500X	Z4	ZO = 10.11 Ohms, Lambda = 0.0392
C6, C7	120 pF Chip Capacitors, ATC #100B12R1CCA500X	Z5	ZO = 6.34 Ohms, Lambda = 0.0711
C9, C12	0.1 μ F Chip Capacitors, Kemet #CDR33BX104AKWS	Z6	ZO = 5.02 Ohms, Lambda = 0.0476
C10, C11	1000 pF Chip Capacitors, ATC #100B102JCA50X	Z7	ZO = 5.54 Ohms, Lambda = 0.0972
C13, C17	22 μ F, 35 V Tantalum Chip Capacitors, Kemet #T491X226K035AS4394	Z8	ZO = 50.0 Ohms, Lambda = 0.194
C14, C16	10 μ F, 35 V Tantalum Chip Capacitors, Kemet #T495X106K035AS4394	Z9	ZO = 50.0 Ohms
C15, C19	1 μ F, 35 V Tantalum Chip Capacitors, Kemet #T495X105K035AS4394	Raw PCB Material	0.030" Glass Teflon [®] , $\epsilon_r = 2.55$, 2 oz Copper, 3" x 5" Dimensions

Figure 1. MRF19090 Test Circuit Schematic



Freescle has begun the transition of marking Printed Circuit Boards (PCBs) with the Freescle Semiconductor signature/logo. PCBs may have either Motorola or Freescle markings during the transition period. These changes will have no impact on form, fit or function of the current product.

Figure 2. MRF19090 Test Circuit Component Layout

TYPICAL CHARACTERISTICS

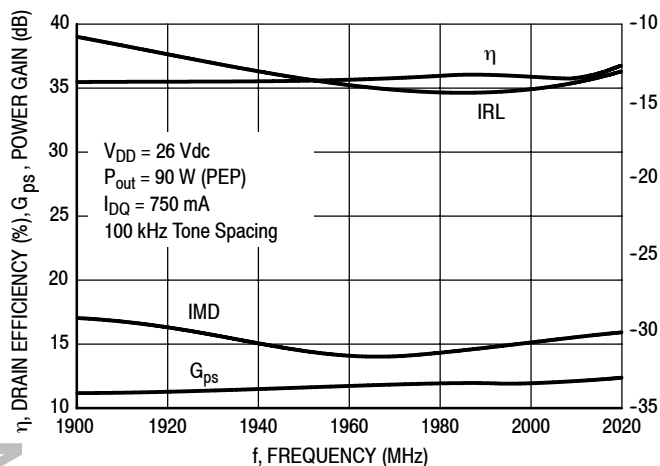


Figure 3. Class AB Performance versus Frequency

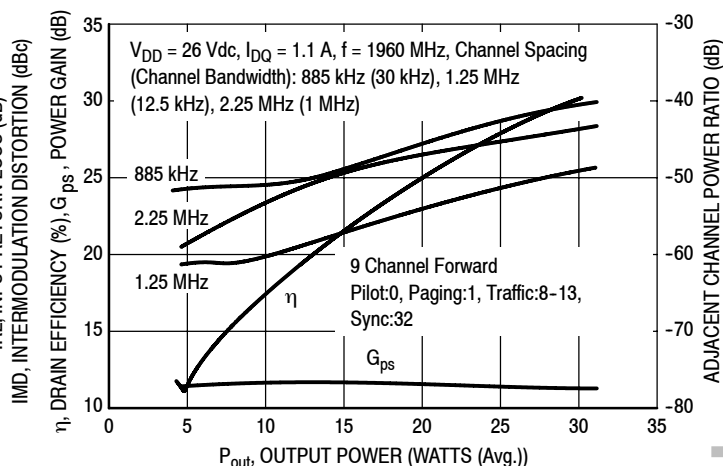


Figure 4. CDMA Performance ACPR, Gain and Drain Efficiency versus Output Power

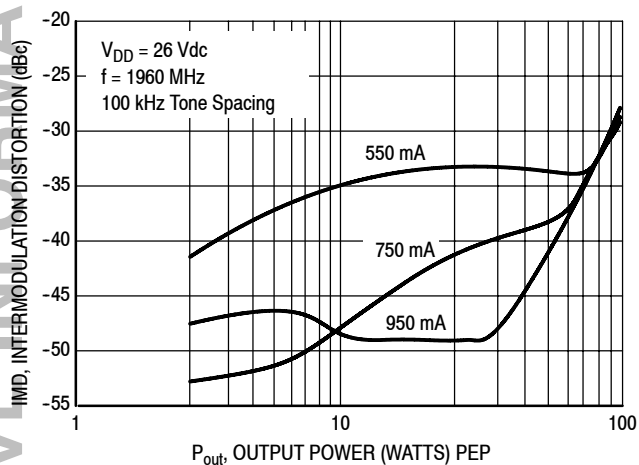


Figure 5. Third Order Intermodulation Distortion versus Output Power

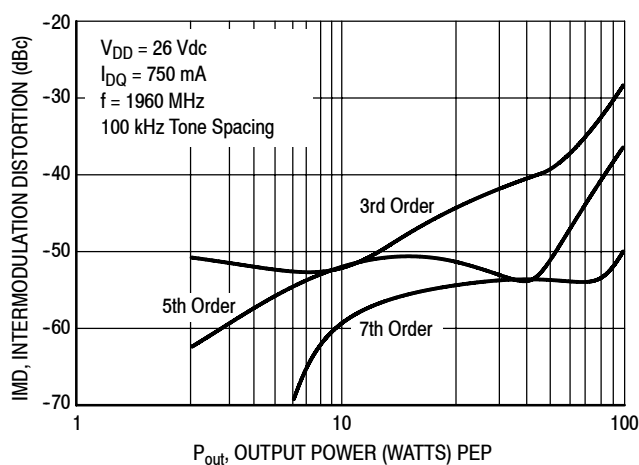


Figure 6. Intermodulation Products versus Output Power

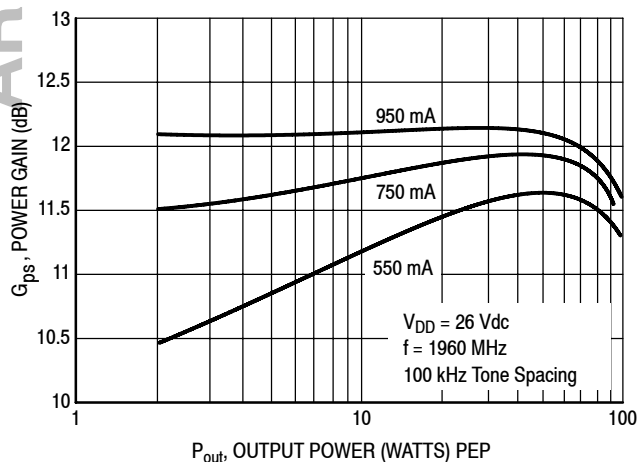


Figure 7. Power Gain versus Output Power

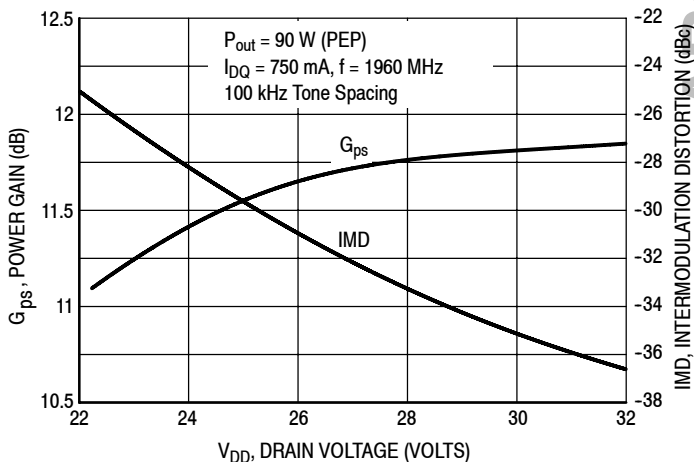
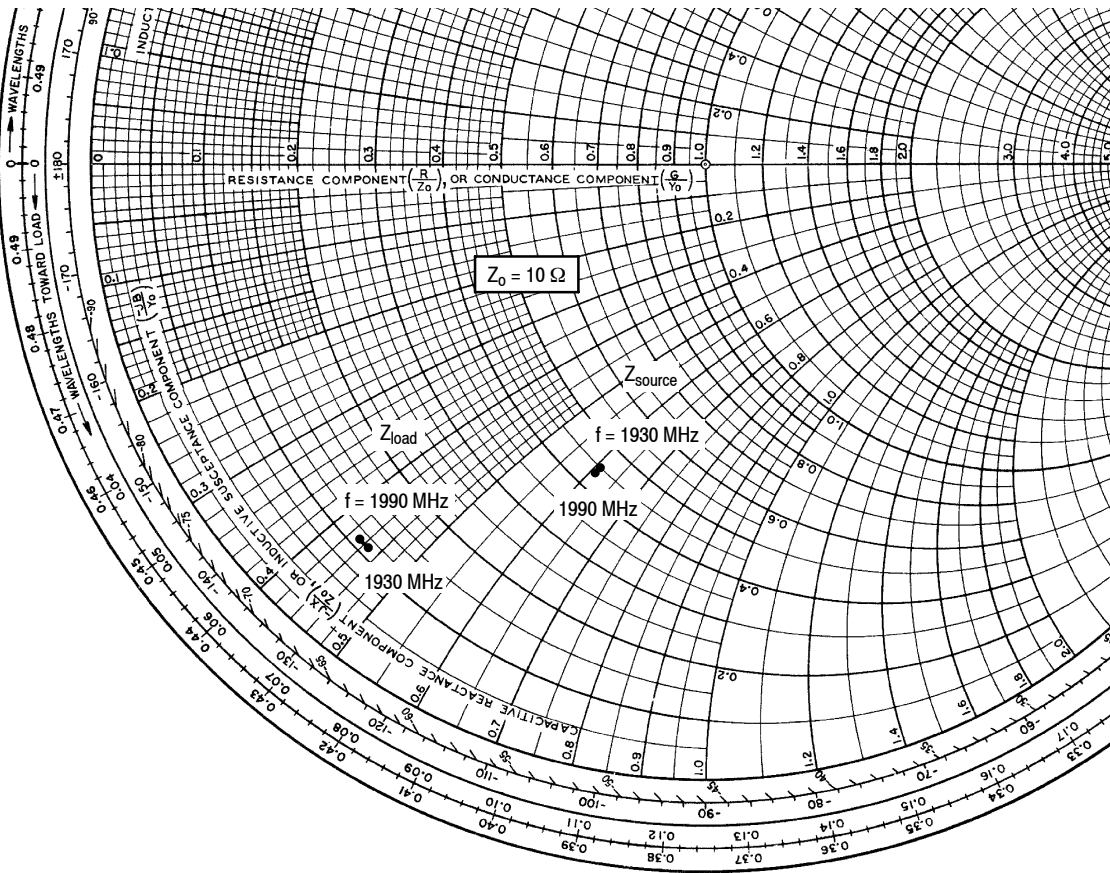


Figure 8. Third Order Intermodulation Distortion and Gain versus Supply Voltage

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$V_{DD} = 26\text{ V}$, $I_{DQ} = 750\text{ mA}$, $P_{out} = 90\text{ Watts (PEP)}$

f MHz	Z_{source} Ω	Z_{load} Ω
1930	$4.5 - j6.1$	$1.1 - j4.5$
1960	$4.4 - j6.0$	$1.1 - j4.4$
1990	$4.3 - j6.1$	$1.1 - j4.3$

Z_{source} = Test circuit impedance as measured from gate to ground.

Z_{load} = Test circuit impedance as measured from drain to ground.

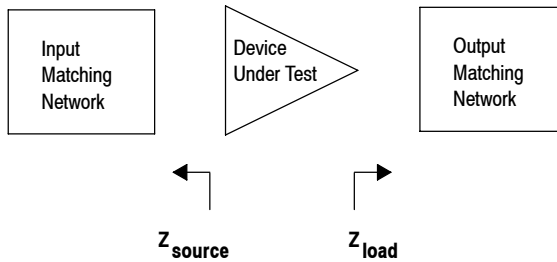
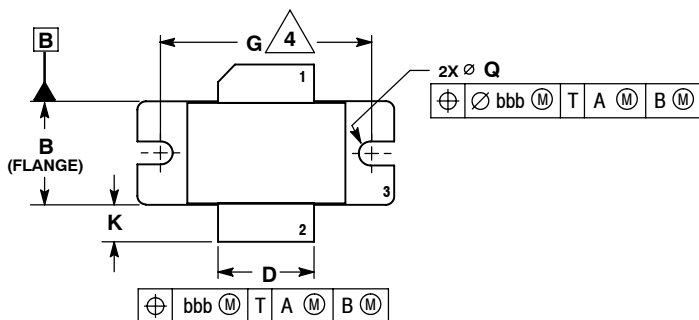


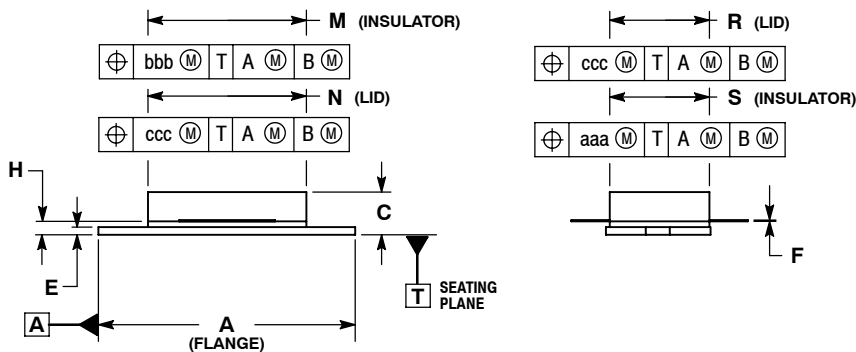
Figure 9. Series Equivalent Source and Load Impedance

PACKAGE DIMENSIONS



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M-1994.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION H IS MEASURED 0.030 (0.762) AWAY FROM PACKAGE BODY.
 4. RECOMMENDED BOLT CENTER DIMENSION OF 1.16 (29.57) BASED ON M3 SCREW.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	1.335	1.345	33.91	34.16
B	0.535	0.545	13.6	13.8
C	0.147	0.200	3.73	5.08
D	0.495	0.505	12.57	12.83
E	0.035	0.045	0.89	1.14
F	0.003	0.006	0.08	0.15
G	1.100 BSC		27.94 BSC	
H	0.057	0.067	1.45	1.70
K	0.175	0.205	4.44	5.21
M	0.872	0.888	22.15	22.55
N	0.871	0.889	19.30	22.60
Q	∅.118	∅.138	∅3.00	∅3.51
R	0.515	0.525	13.10	13.30
S	0.515	0.525	13.10	13.30
aaa	0.007 REF		0.178 REF	
bbb	0.010 REF		0.254 REF	
ccc	0.015 REF		0.381 REF	

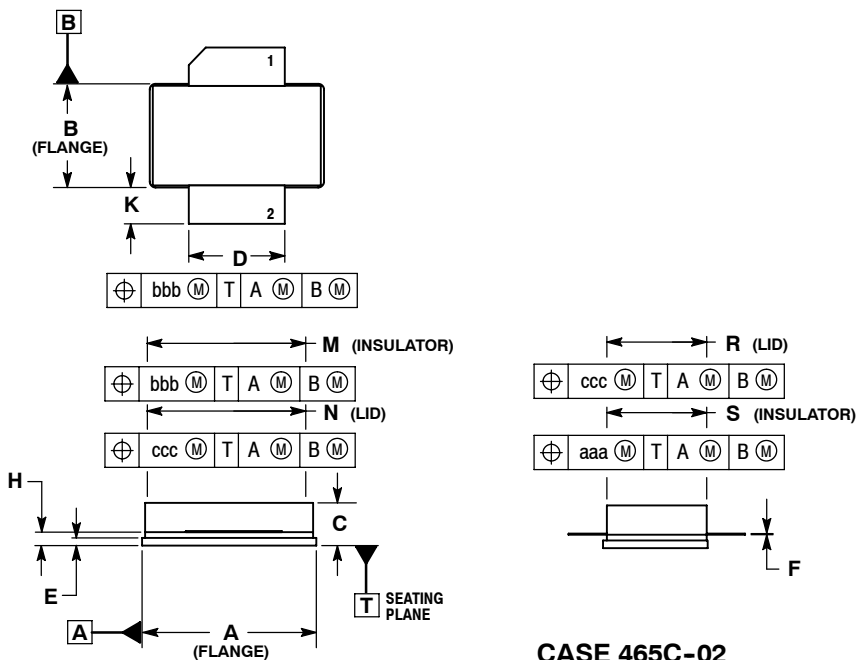


- STYLE 1:
 PIN 1. DRAIN
 PIN 2. GATE
 PIN 3. SOURCE

**CASE 465B-03
 ISSUE D
 NI-880
 MRF19090R3**

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- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M-1994.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION H IS MEASURED 0.030 (0.762) AWAY FROM PACKAGE BODY.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.905	0.915	22.99	23.24
B	0.535	0.545	13.60	13.80
C	0.147	0.200	3.73	5.08
D	0.495	0.505	12.57	12.83
E	0.035	0.045	0.89	1.14
F	0.003	0.006	0.08	0.15
H	0.057	0.067	1.45	1.70
K	0.170	0.210	4.32	5.33
M	0.872	0.888	22.15	22.55
N	0.871	0.889	19.30	22.60
R	0.515	0.525	13.10	13.30
S	0.515	0.525	13.10	13.30
aaa	0.007 REF		0.178 REF	
bbb	0.010 REF		0.254 REF	
ccc	0.015 REF		0.381 REF	

- STYLE 1:
 PIN 1. DRAIN
 PIN 2. GATE
 PIN 3. SOURCE

**CASE 465C-02
 ISSUE D
 NI-880S
 MRF19090SR3**

REVISION HISTORY

The following table summarizes revisions to this document.

Revision	Date	Description
6	Dec. 2010	<ul style="list-style-type: none"> • MRF19090 Rev. 6 data sheet archived. Data sheet split due to change in part life cycle. See MRF19090-1 Rev. 7 for MRF19090R3 and MRF19090-2 Rev. 8 for MRF19090SR3.

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